



# Free-electron laser extreme ultraviolet lithography: considerations for high-volume manufacturing

Erik R. Hosler, Obert R. Wood II, Moshe E. Preil

**GLOBALFOUNDRIES**

William A. Barletta

**Massachusetts Institute of Technology**



**GLOBALFOUNDRIES®**

# Extreme-Ultraviolet Lithography High-Volume Manufacturing

- **An EUV high-volume manufacturing (HVM) source has yet to be demonstrated**
- Will laser-produced plasma (LPP) execute to HVM powers, or is another source required?
  - Current EUVL tools are targeting 500 exposures per day at  $15 \text{ mJ/cm}^2$
  - A mature HVM technology may require upwards of 50k wafers per month
  - 5-10 EUV layers at 7 nm node
  - Possible  $>50 \text{ mJ/cm}^2$  dose requirement
- Enter Free-Electron Lasers (FELs)
- LPP development and deployment must continue if EUVL is to enter HVM

LPP EUV Source Plasma Chamber

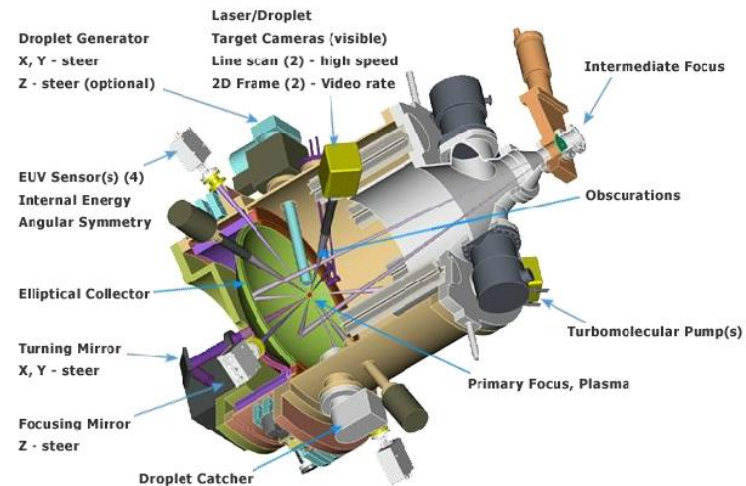
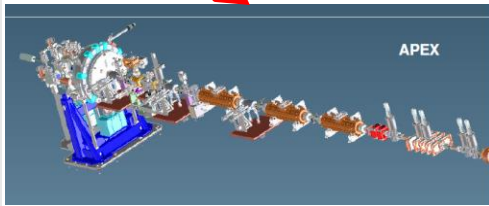
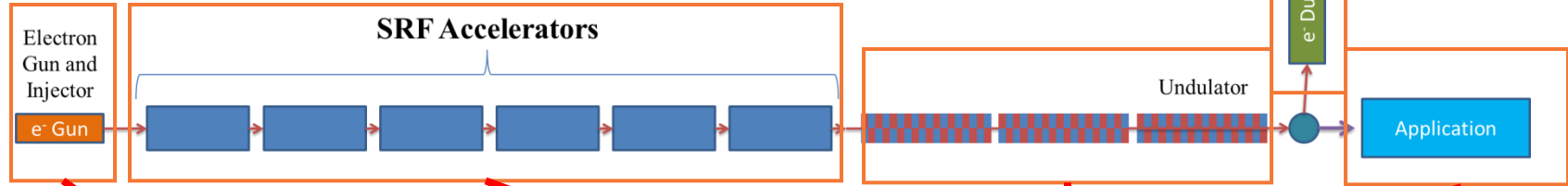


Photo Credits: Cymer



# Free-Electron Lasers Designs



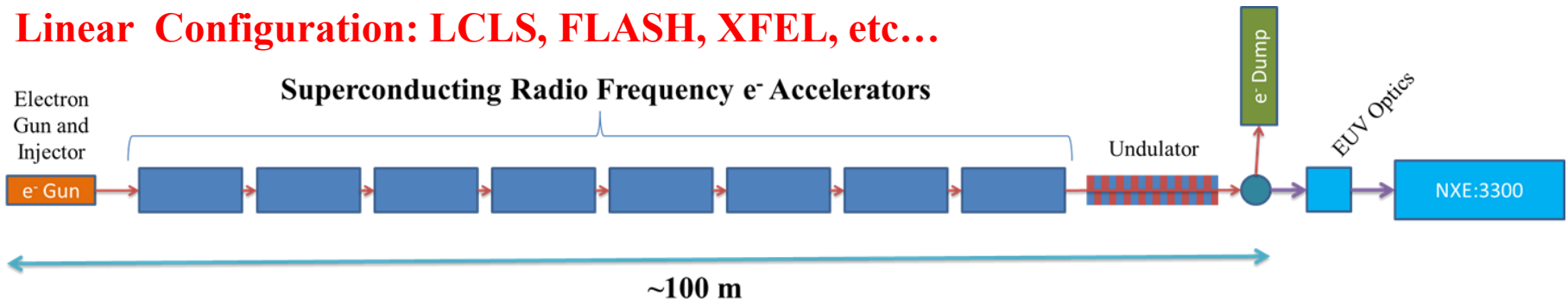
- FEL machine components:
  - **e<sup>-</sup> source/gun and injector**: generates and prepares e<sup>-</sup> bunch (overcome space charge effects)
  - **Linac (superconducting radio frequency (SRF) cavities)**: accelerates e<sup>-</sup> beam to relativistic speeds
  - **Undulator**: radiator, wiggles e<sup>-</sup> packet
  - **e<sup>-</sup> beam dump**: radiation source, must absorb enormous power
  - **End station**: EUV beam delivery and manipulation optics to multiple scanners
- Where can cost, efficiency, and reliability be optimized?
- Accomplished in Academia vs. Technologically Feasible

# Lithographic Requirements

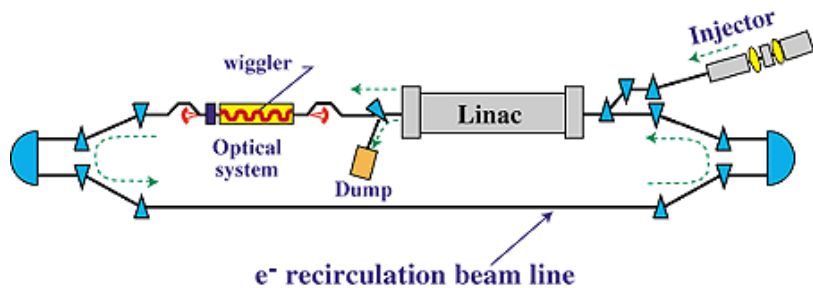
- An EUV FEL must power multiple scanners simultaneously
- **FEL EUV source must operate with an availability of 100%**
  - Redundancy of high-risk/low-cost machine components
  - Minimizing stress on long replacement time components
  - **Two FELs must be run simultaneously!**
- **Cost**
  - FEL EUV program must be substantially cheaper (depreciation + OpEx) and more powerful than an equivalent number of LPP sources to justify development risk
  - How many EUVL sources are required for HVM?
    - 7 nm Logic roadmap from IMEC says 5-10 EUV layers
    - 3-4 L/S ( $>25 \text{ mJ/cm}^2$ ), 2-6 contact ( $>35 \text{ mJ/cm}^2$ ) = 10x 250 W LPP tools for ~50k wafers/month
- **Other: FEL Specific**
  - Beam Distribution
    - High power, splitting efficiency
  - Power management and Facility Size
    - On mask, on mirrors, on wafer, into beam dump, and electrical power
    - Integrate with existing fab architecture
  - Coherence
    - Manipulate at scanner (Extended Flex-OAI?) or within distribution system
  - Harmonic mitigation scheme
    - FELs produce a few percent of the fundamental power in higher harmonics
  - **Wavelength stability? Optical bandwidth? Power stability (Dose repro  $<0.2\%$ )?**

# FEL Layout: Two Promising Configurations

## Linear Configuration: LCLS, FLASH, XFEL, etc...

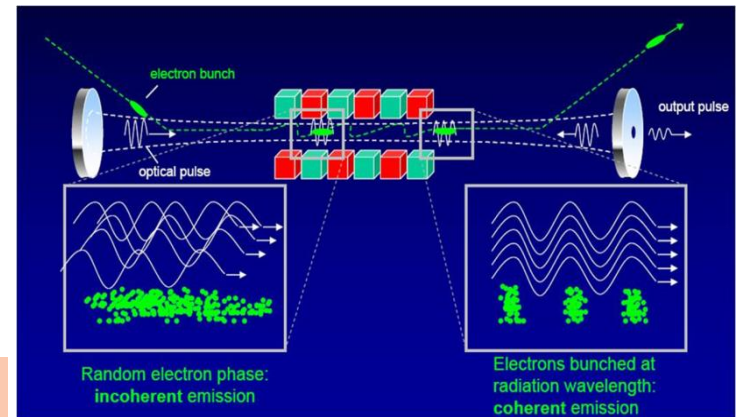


## JLab IR Demo: Oscillator Multi-Pass Linac



*Conducive to electron beam energy recovery.*

## Los Alamos Regenerative Amplifier FEL: RAFEL





# Cost of LPP vs. FEL for HVM

(\$M/year)		250 W LPP Sources	10 kW EUV ERL FEL (Scanners Powered @ 1 kW)
OpEx		8.5 <sup>a</sup>	23
CapEx		25.6 <sup>b</sup>	240
Cost per Source, First Year <sup>c</sup>		34.1	263
Cost to Power 10 Scanners	OpEx	85	23
	CapEx	256	240
	Total Cost First Year <sup>c</sup>	>341	263
	FEL Savings Each Year <sup>d</sup>		<u>&gt;60</u>
Uptime Per Source		Target 90%	~100%
Average Exposures Per Day (10 Scanners, Dose: 25 mJ/cm <sup>2</sup> )		13,280 <sup>e</sup>	29,700

<sup>a</sup> LPP OpEx estimates from public source requirements and component lifetimes.

<sup>b</sup> LPP source (2013 configuration) cost from ABN AMRO Bank report on ASML: 8/21/2013.

<sup>c</sup> CapEx is fully depreciated in the first year to simplify projections.

<sup>d</sup> FEL savings are calculated after first year, once the sources are fully depreciated

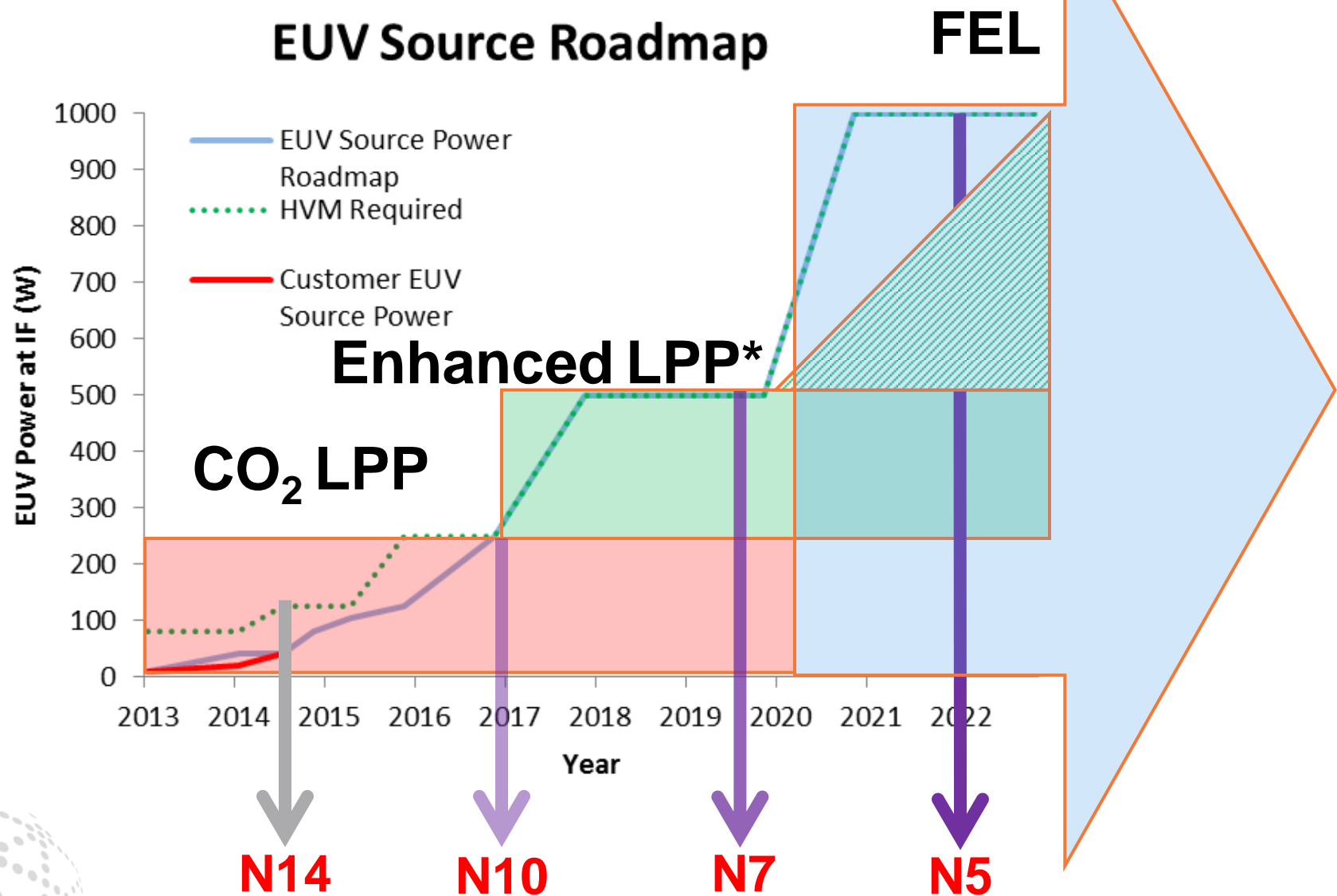
<sup>e</sup> Calculation of throughput aligns with the current 500 WPD at 100% uptime, 15 mJ/cm<sup>2</sup> prediction.

FEL estimates represent a first level approximation of the cost associated with a recirculating Linac operating in a RAFEL mode. Estimates were developed from numerous technical design reports of existing and planned accelerators and free-electron laser facilities as well as quotes from various vendors (Linde, Radiabeam, and Kyma).

# Interaction Between Customer and Integrator

- A vendor or large manufacturing entity will be need to act as the FEL facility integrator
  - Integrator will bring multiple independent sources together for FEL construction, previously, government labs held this role
  - Most FEL equipment has been commercialized:
    - undulator, vacuum equipment, RF systems, cryomodules, cryogenic plant
  - Specialized manufacturing will revolve around the FEL configuration and injector/electron gun assembly
  - Research Labs will provide key information regarding FEL construction and operation and will quite possibly play a critical role in daily FEL operation
    - Each customer site will bring its unique set or requirements and the first generation of machines after a demo will only be a few (x2 at each site though). FELs inherently lend themselves to flexible requirements.
  - ASML will need to ensure FEL integration with NXE tool series

# Free-Electron Lasers as an Alternative to LPP

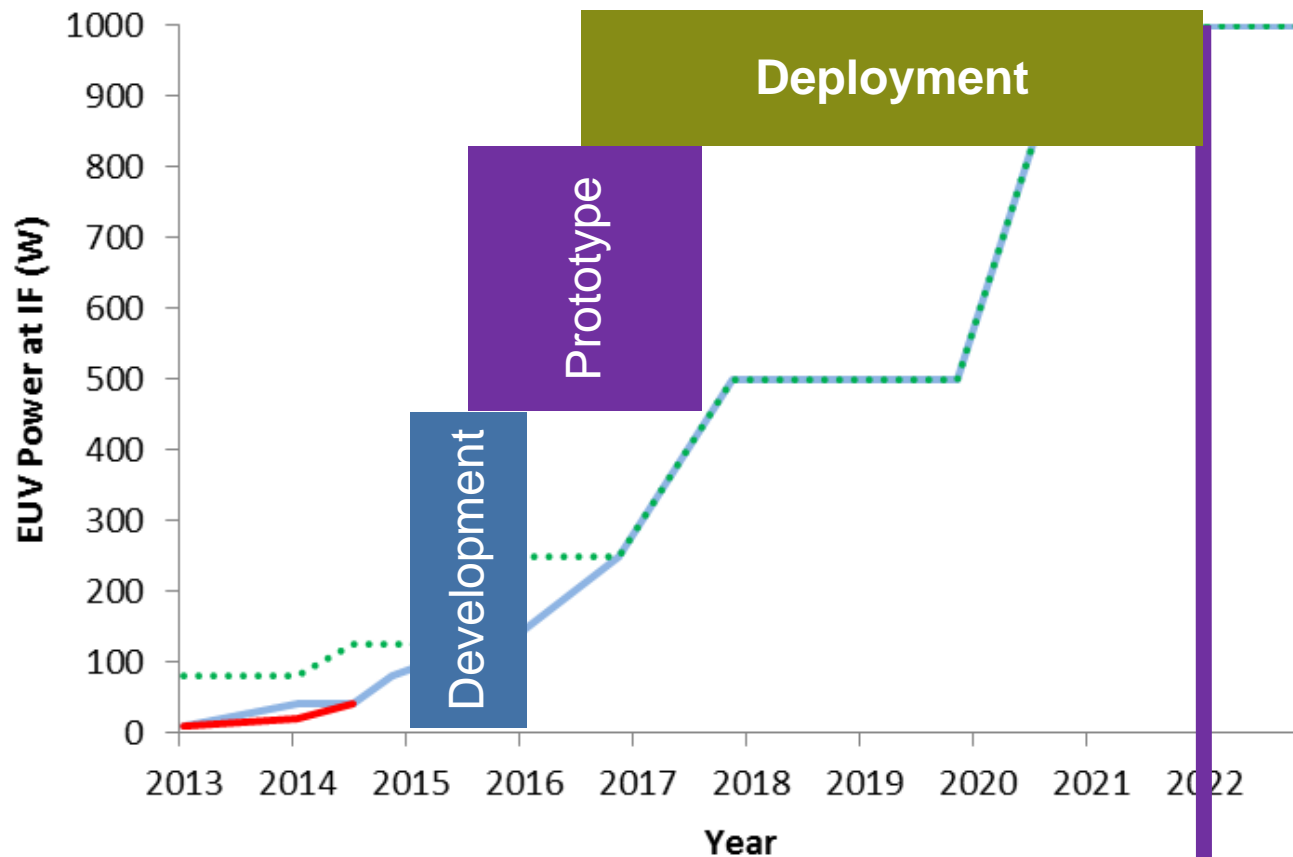


\*Possibly YAG Pre-Pulse + CO<sub>2</sub> Main Pulse LPP or other innovations  
Gigaphoton press release: <http://optics.org/news/3/7/6>  
Nishihara, K., et al. EUVL 2008. Tahoe.  
Reported EUV source powers and roadmap targets are from ASML/other public announcements.



# Free-Electron Lasers as an Alternative to LPP

## EUV Source Roadmap



N5

\*Possibly YAG Pre-Pulse + CO<sub>2</sub> Main Pulse LPP or other innovations  
Gigaphoton press release: <http://optics.org/news/3/7/6>  
Nishihara, K., et al. EUVL 2008. Tahoe.  
Reported EUV source powers and roadmap targets are from ASML/other public announcements.

Additional Contributors:

Pawitter Mangat  
**GLOBALFOUNDRIES**

**Thank you**

Erik R. Hosler, Ph.D.

[Erik.Hosler@GLOBALFOUNDRIES.COM](mailto:Erik.Hosler@GLOBALFOUNDRIES.COM), 518-305-1963



**GLOBALFOUNDRIES®**